
FAIRCHILD

A Schlumberger Company

MIL-STD-883

July 1986—Rev 2⁵

μ A78M06QB 3-Terminal Positive Voltage Regulator

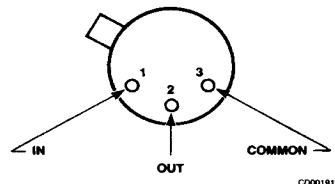
Aerospace and Defense Data Sheet

Linear Products

Description

The μ A78M06QB 3-Terminal Medium Current Positive Voltage Regulator is constructed using the Fairchild Planar Epitaxial process. This regulator employs internal current-limiting, thermal shutdown and safe-area compensation, making it essentially indestructible. If adequate heat sinking is provided, it can deliver in excess of 500 mA output current. It is intended as a fixed voltage regulator in a wide range of applications including local, on-card regulation for elimination of noise and distribution problems associated with single point regulation. In addition to use as a fixed voltage regulator, this device can be used with external components to obtain adjustable output voltages and currents.⁶

- Output Current In Excess Of 0.5 A
- No External Components
- Internal Thermal Overload Protection
- Internal Short Circuit Current-Limiting
- Output Transistor Safe-Area Compensation

**Connection Diagram
3-Lead TO-39 Can
(Top View)**

Lead 3 connected to case.

Order Information

Part No.	Case/ Finish	Package Code
μ A78M06HMQB	XC	Mil-M-38510, Appendix C 3-Lead Can

Absolute Maximum Ratings

Storage Temperature Range	−65°C to +175°C
Operating Temperature Range	−55°C to +125°C
Lead Temperature (soldering, 60 s)	300°C
Internal Power Dissipation ⁹	
Can Without Heat Sink ¹⁰	0.18 W
Can With Heat Sink ¹¹	0.5 W
Input Voltage	35 V

Processing: MIL-STD-883, Method 5004

Burn-In: Method 1015, Condition A, PDA calculated using Method 5005, Subgroup 1

Quality Conformance Inspection: MIL-STD-883, Method 5005

Group A Electrical Tests Subgroups:

1. Static tests at 25°C
2. Static tests at 125°C
3. Static tests at −55°C
4. Dynamic tests at 25°C
9. AC tests at 25°C

Group C and D Endpoints: Group A, Subgroup 1

Notes

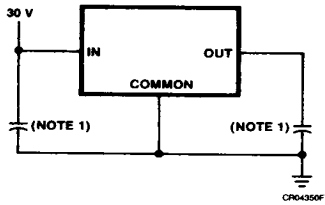
1. 100% Test and Group A
2. Group A
3. Periodic tests, Group C
4. Guaranteed but not tested
5. When changes occur, FSC will make data sheet revisions available. Contact local sales representative for the latest revision.
6. For more information on device function, refer to the Fairchild Linear Data Book Commercial Section.
7. All characteristics except line and load transient response and noise are measured using pulse techniques ($t_W \leq 10$ ms, duty cycle $\leq 5\%$). Output voltage changes due to changes in the internal temperature must be taken into account separately.
8. Conditions given will result in the following: $P_D \leq 4$ W.
9. Internally limited.
10. Rating applies to ambient temperatures up to 125°C. Above 125°C, derate linearly at 140°C/W.
11. Rating applies to ambient temperatures up to 125°C. Above 125°C, derate linearly at 50°C/W.

μA78M06QB

Electrical Characteristics $V_I = 11\text{ V}$, $I_L = 350\text{ mA}$, $C_I = 0.33\text{ }\mu\text{F}$, $C_O = 0.1\text{ }\mu\text{F}$, unless otherwise specified.⁷

Symbol	Characteristic	Condition	Min	Max	Unit	Note	Subgrp	
V _O	Output Voltage ⁸		5.75	6.25	V	1	1	
		5.0 mA ≤ I _L ≤ 350 mA	V _I = 9.0 V	5.7	6.3	V	1	1,2,3
			V _I = 21 V	5.7	6.3	V	1	1,2,3
ΔV _O /ΔT	Average Temperature Coefficient of Output Voltage	I _L = 5.0 mA, 25°C ≤ T _A ≤ 125°C		1.5	mV/°C	4	2	
		I _L = 5.0 mA, −55°C ≤ T _A ≤ 25°C		2.0	mV/°C	4	3	
V _{R LINE}	Line Regulation	8.0 V ≤ V _I ≤ 25 V, I _L = 200 mA		60	mV	1	1	
		9.0 V ≤ V _I ≤ 20 V, I _L = 200 mA		30	mV	1	1	
V _{R LOAD}	Load Regulation	5.0 mA ≤ I _L ≤ 500 mA		60	mV	1	1	
		5.0 mA ≤ I _L ≤ 200 mA		30	mV	1	1	
I _{SCD}	Standby Current Drain			7.0	mA	1	1	
ΔI _{SCD} (LINE)	Standby Current Drain Change (vs Line Voltage)	9.0 V ≤ V _I ≤ 25 V, I _L = 200 mA		0.8	mA	1	1,2,3	
ΔI _{SCD} (LOAD)	Standby Current Drain Change (vs Load Current)	5.0 mA ≤ I _L ≤ 350 mA		0.5	mA	1	1,2,3	
V _{DO}	Dropout Voltage			2.5	V	1	1	
I _{OS}	Output Short Circuit Current	V _I = 35 V		1.0	A	1	1	
I _{OL}	Overload Current	V _I = 13 V	0.5	2.0	A	1	1	
ΔV _I /ΔV _O	Ripple Rejection	V _I = 11 V, I _L = 125 mA, e _i = 1.0 V _{rms} , f = 2400 Hz	59		dB	1	4	
N _O	Noise	V _I = 11 V, I _L = 50 mA, 10 Hz ≤ f ≤ 10 kHz		125	μV _{rms}	4	9	

Primary Burn-In Circuit



Note

1. Capacitor value necessary to suppress oscillations.

Equivalent Circuit

